PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

Rev. 7 — 5 December 2011

Product data sheet

1. Product profile

1.1 General description

PNP Resistor-Equipped Transistor (RET) family in Surface-Mounted Device (SMD) plastic packages.

Table 1. Product overview

Type number	Package			NPN	Package	
	NXP	JEITA	JEDEC	complement	configuration	
PDTA143ZE	SOT416	SC-75	-	PDTC143ZE	ultra small	
PDTA143ZM	SOT883	SC-101	-	PDTC143ZM	leadless ultra small	
PDTA143ZT	SOT23	-	TO-236AB	PDTC143ZT	small	
PDTA143ZU	SOT323	SC-70	-	PDTC143ZU	very small	

1.2 Features and benefits

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design

1.3 Applications

- Digital applications in automotive and industrial segments
- Control of IC inputs

- Reduces component count
- Reduces pick and place costs
- AEC-Q101 qualified
- Cost-saving alternative for BC847/857 series in digital applications
- Switching loads

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
V _{CEO}	collector-emitter voltage	open base	-	-	-50	V
lo	output current		-	-	-100	mA
R1	bias resistor 1 (input)		3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		8	10	12	



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2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
SOT23; S	OT323; SOT416		
1	input (base)		
2	GND (emitter)	3	
3	output (collector)	12	1 R1 R2 sym003
SOT883			
1	input (base)		
2	GND (emitter)	1 3	
3	output (collector)	2 Transparent top view	1 R1 R2 R2 sym003

3. Ordering information

Type number	Package	Package					
	Name	Description	Version				
PDTA143ZE	SC-75	plastic surface-mounted package; 3 leads	SOT416				
PDTA143ZM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 \times 0.6 \times 0.5 mm	SOT883				
PDTA143ZT	-	plastic surface-mounted package; 3 leads	SOT23				
PDTA143ZU	SC-70	plastic surface-mounted package; 3 leads	SOT323				

4. Marking

Table 5. Marking codes	
Type number	Marking code ^[1]
PDTA143ZE	37
PDTA143ZM	DP
PDTA143ZT	*19
PDTA143ZU	*47

[1] * = placeholder for manufacturing site code

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5. Limiting values

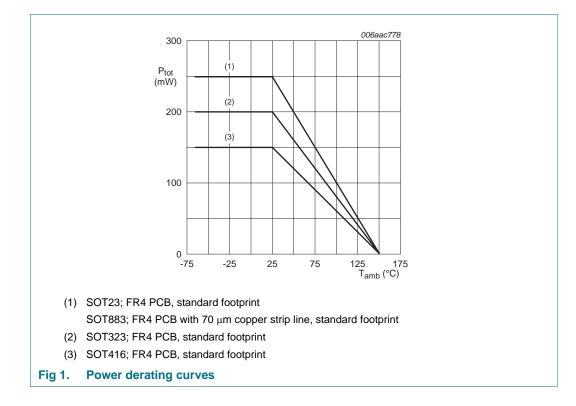
Symbol	Parameter	Conditions	Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter	-	-50	V
V _{CEO}	collector-emitter voltage	open base	-	-50	V
V _{EBO}	emitter-base voltage	open collector	-	-5	V
VI	input voltage				
	positive		-	+5	V
	negative		-	-30	V
lo	output current		-	-100	mA
I _{CM}	peak collector current	single pulse; $t_p \leq 1 ms$	-	-100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 \ ^{\circ}C$			
	PDTA143ZE (SOT416)		<u>[1][2]</u> _	150	mW
	PDTA143ZM (SOT883)		[2][3]	250	mW
	PDTA143ZT (SOT23)		<u>[1]</u> -	250	mW
	PDTA143ZU (SOT323)		<u>[1]</u> -	200	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 70 µm copper strip line, standard footprint.

PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω



6. Thermal characteristics

Table 7.	Thermal characteristics						
Symbol	Parameter	Conditions	Ν	<i>l</i> in	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from junction to ambient	in free air					
	PDTA143ZE (SOT416)		<u>[1][2]</u> _		-	830	K/W
	PDTA143ZM (SOT883)		[2][3]		-	500	K/W
	PDTA143ZT (SOT23)		<u>[1]</u> _		-	500	K/W
	PDTA143ZU (SOT323)		<u>[1]</u> _		-	625	K/W

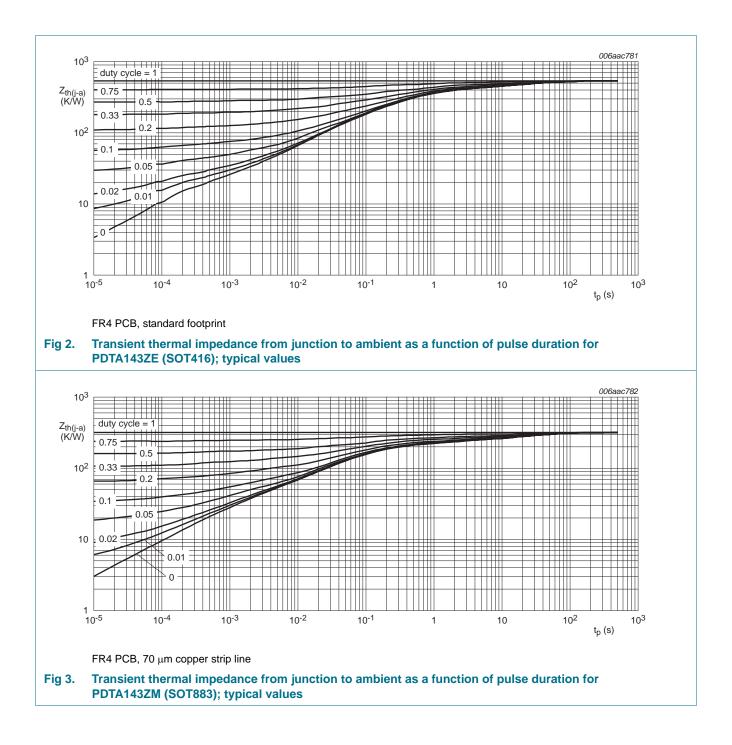
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Reflow soldering is the only recommended soldering method.

[3] Device mounted on an FR4 PCB with 70 μ m copper strip line, standard footprint.

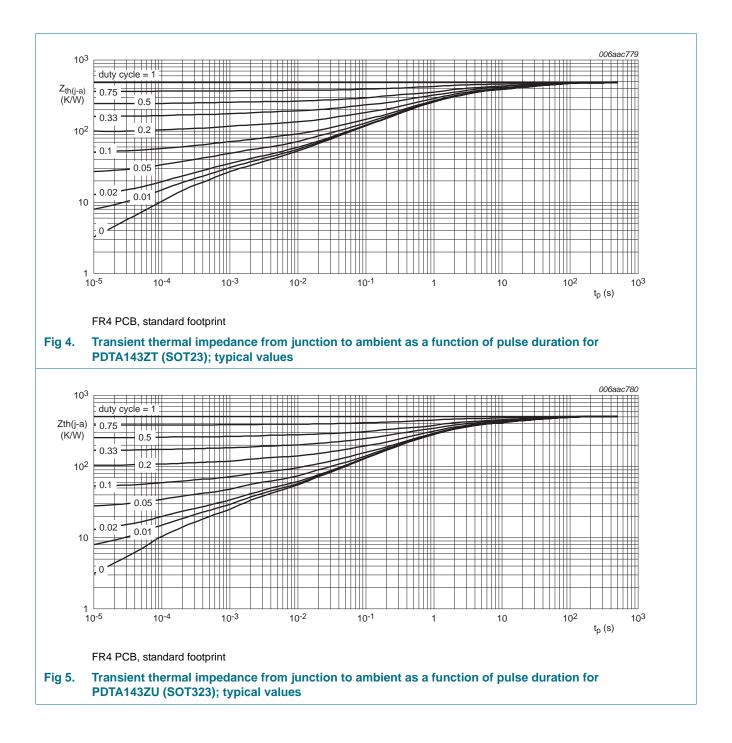
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PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω



PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

7. Characteristics

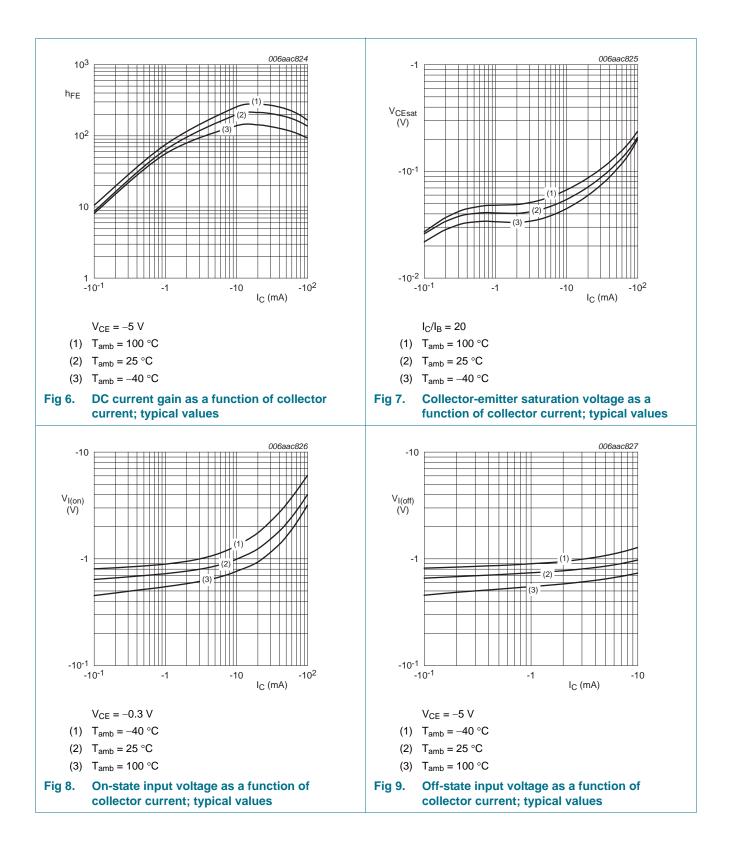
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
I _{CBO}	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$	-	-	-100	nA
I _{CEO}	collector-emitter	V_{CE} = -30 V; I _B = 0 A	-	-	-1	μΑ
	cut-off current	$V_{CE} = -30 \text{ V}; I_B = 0 \text{ A};$ $T_j = 150 \text{ °C}$	-	-	-5	μA
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; \text{ I}_{C} = 0 \text{ A}$	-	-	-170	μA
h _{FE}	DC current gain	V_{CE} = -5 V; I _C = -10 mA	100	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_{C} = -5 \text{ mA}; I_{B} = -0.25 \text{ mA}$	-	-	-100	mV
V _{I(off)}	off-state input voltage	V_{CE} = –5 V; I_{C} = –100 μA	-	-0.6	-0.5	V
V _{I(on)}	on-state input voltage	V_{CE} = –0.3 V; I_{C} = –5 mA	-1.3	-0.9	-	V
R1	bias resistor 1 (input)		3.3	4.7	6.1	kΩ
R2/R1	bias resistor ratio		8	10	12	
C _c	collector capacitance	$\label{eq:VCB} \begin{split} V_{CB} &= -10 \text{ V}; \text{ I}_{E} = \text{i}_{e} = 0 \text{ A}; \\ \text{f} &= 1 \text{ MHz} \end{split}$	-	-	3	pF
f _T	transition frequency	$V_{CE} = -5 \text{ V}; \text{ I}_{C} = -10 \text{ mA};$ [1] f = 100 MHz	-	180	-	MHz

[1] Characteristics of built-in transistor

PDTA143Z_SER
Product data sheet

PDTA143Z series

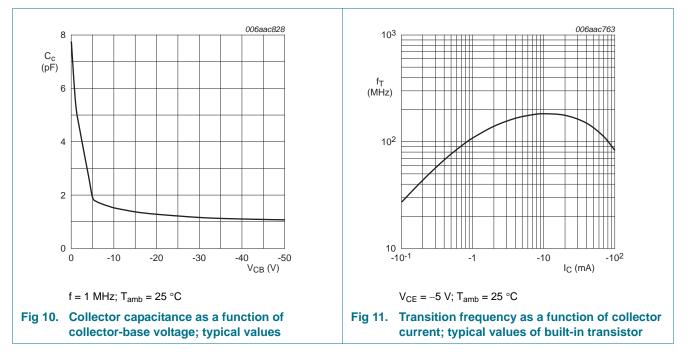
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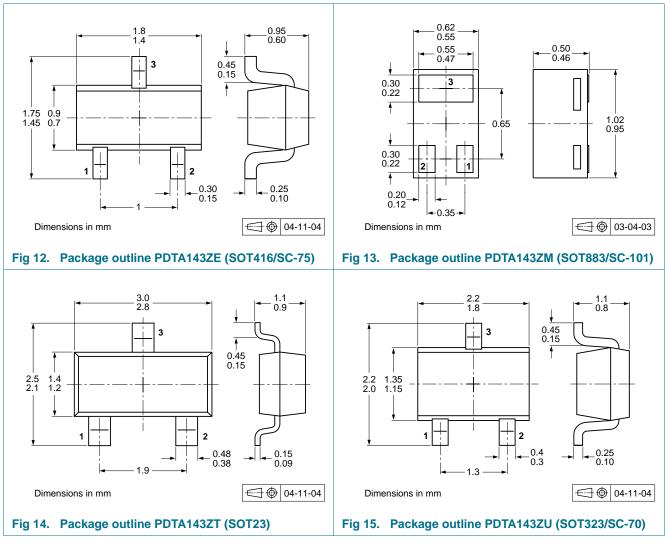
8. Test information

8.1 Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101* - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

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9. Package outline



10. Packing information

Table 9.Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

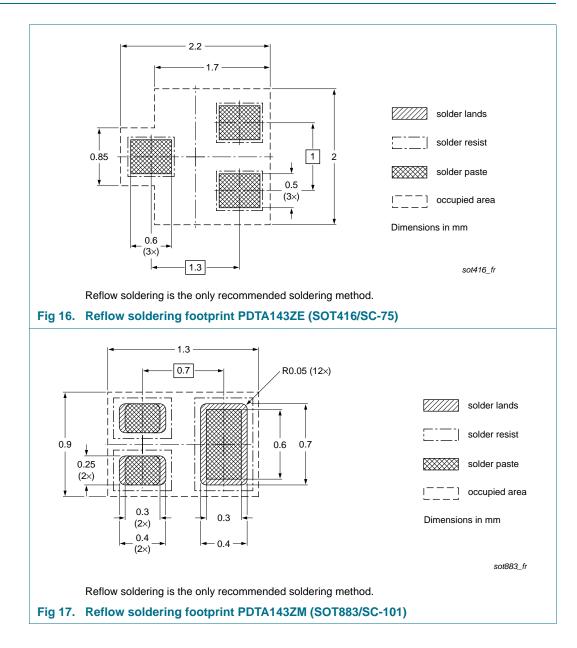
Type number	Package	Description	Packing	Packing quantity		
			3000	5000	10000	
PDTA143ZE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135	
PDTA143ZM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315	
PDTA143ZT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235	
PDTA143ZU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135	

[1] For further information and the availability of packing methods, see Section 14.

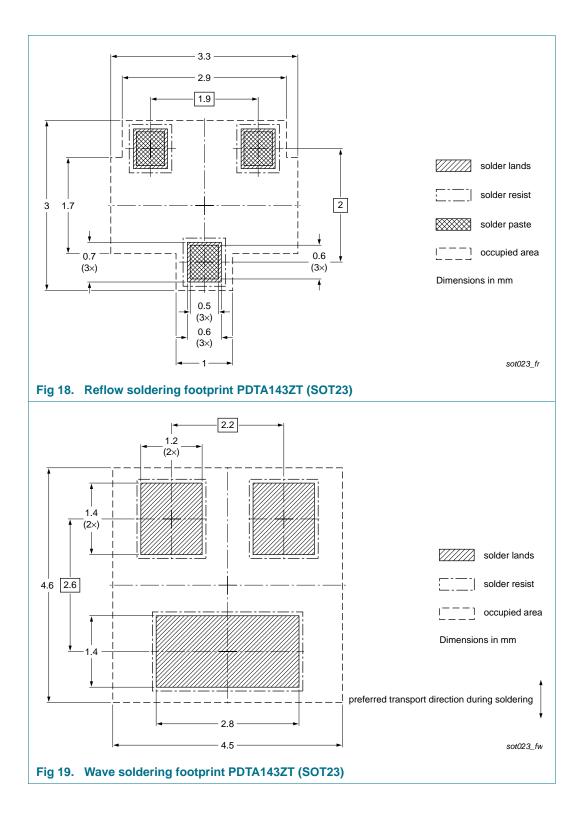
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PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

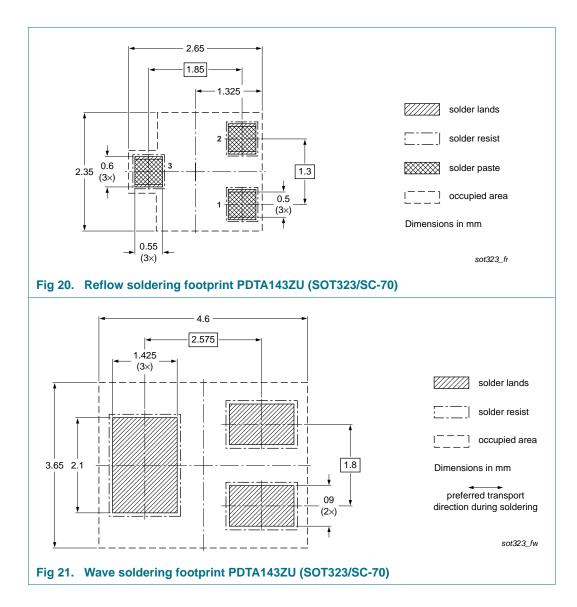
11. Soldering



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PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
PDTA143Z_SER v.7	20111205	Product data sheet	-	PDTA143Z_SERIES v.6			
Modifications:		of this document has been r f NXP Semiconductors.	edesigned to comply w	ith the new identity			
	 Legal texts 	have been adapted to the ne	ew company name whe	ere appropriate.			
	 Type numbers PDTA143ZEF, PDTA143ZK and PDTA143ZS removed. 						
	 <u>Section 1 "Product profile"</u>: updated 						
	 Section 3 "Ordering information": added 						
	 <u>Section 4 "Marking"</u>: updated 						
	• Figure 1 to 11: added						
	 <u>Section 6 "Thermal characteristics"</u>: updated 						
	 <u>Table 8 "Characteristics</u>": V_{i(on)} redefined to V_{I(on)} on-state input voltage, V_{i(off)} redefined to V_{I(off)} off-state input voltage, I_{CEO} updated, f_T added 						
	<u>Section 8 "Test information"</u> : added						
	 Section 9 "F 	ackage outline": supersede	d by minimized packag	e outline drawings			
	Section 10 '	Packing information": addee	t				
	Section 11 "	Soldering": added					
	Section 13 '	Legal information": updated					
PDTA143Z_SERIES v.6	20040805	Product data sheet	-	PDTA143Z_SERIES v.5			
PDTA143Z_SERIES v.5	20030908	Product specification	-	PDTA143Z_SERIES v.4			
PDTA143Z_SERIES v.4	20030410	Product specification	-	-			

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13. Legal information

13.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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PDTA143Z SER

PNP resistor-equipped transistors; R1 = 4.7 k Ω , R2 = 47 k Ω

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PDTA143Z series

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